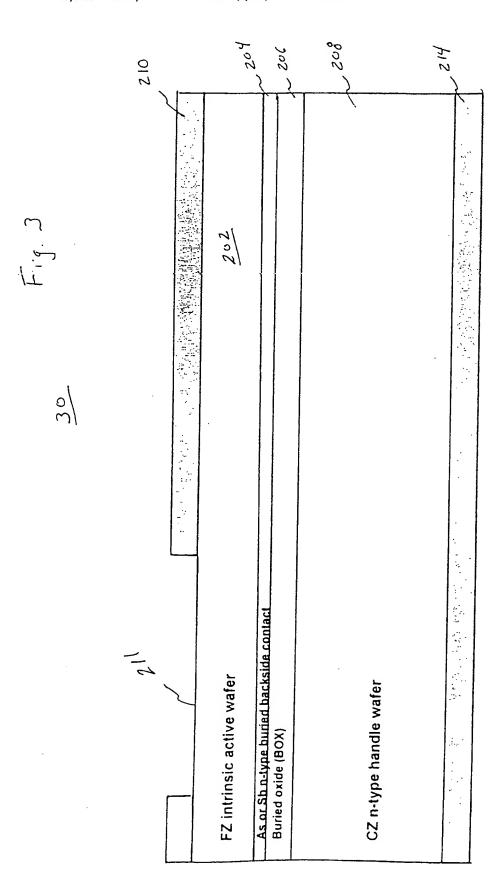
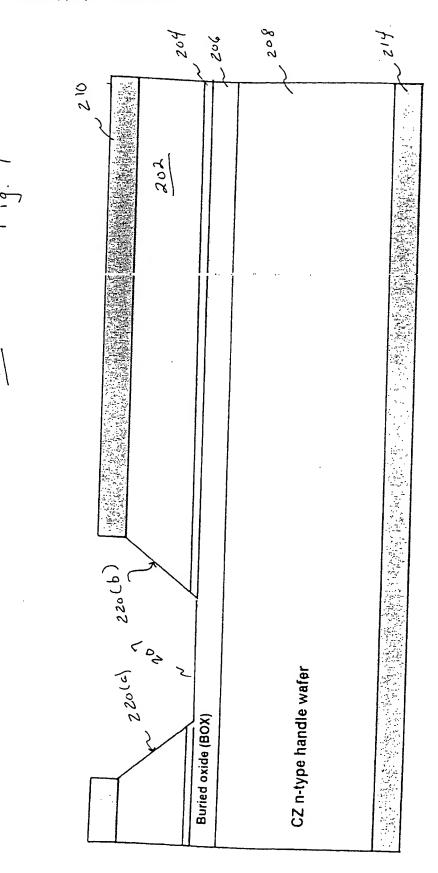
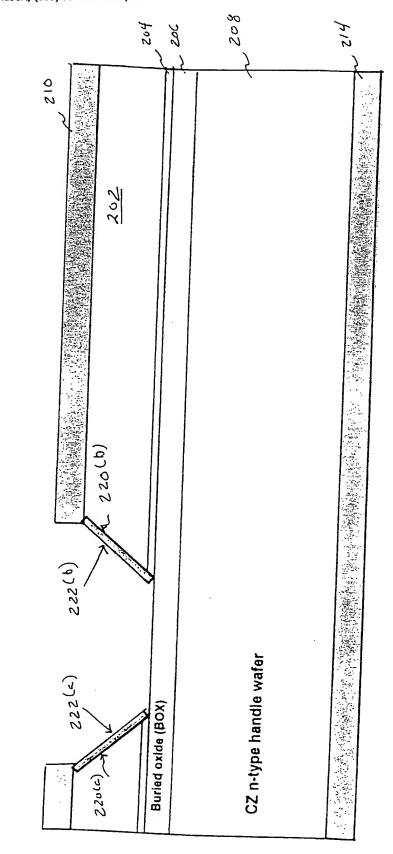
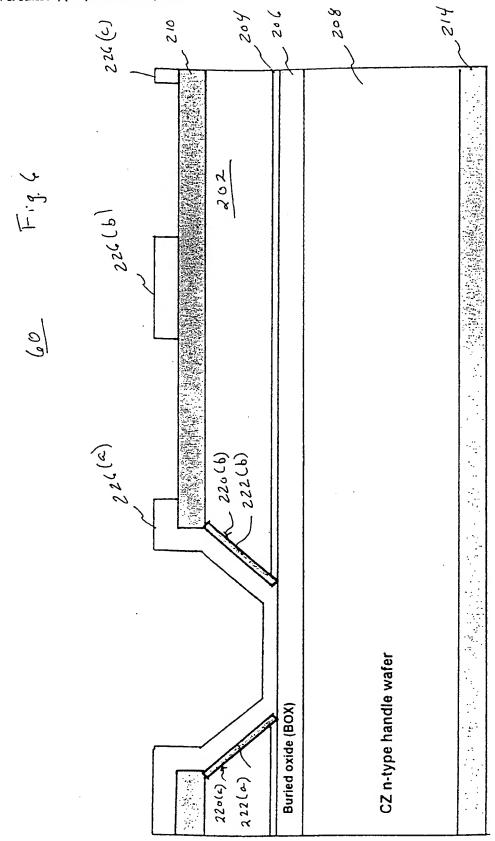


	212	0.7	402	206	208	, h12	216
20 Fig. 2			202				
	112		FZ intrinsic active wafer	As or Sb n-type buried backside contact Buried oxide (BOX)	CZ n-type handle wafer		

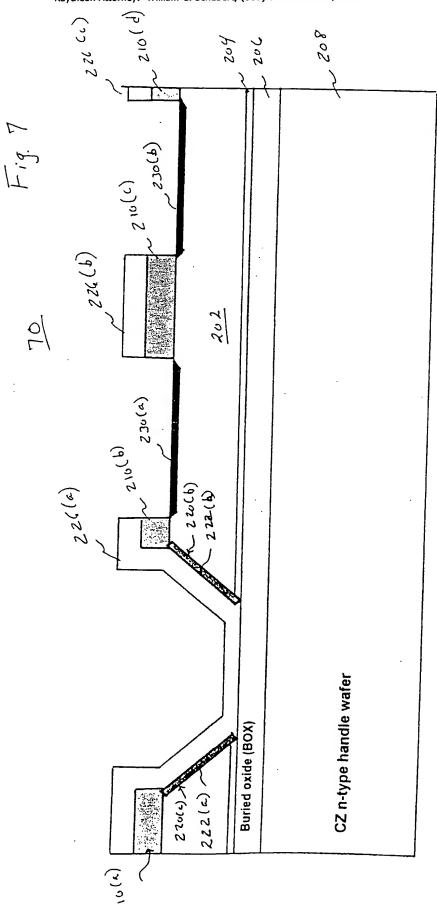


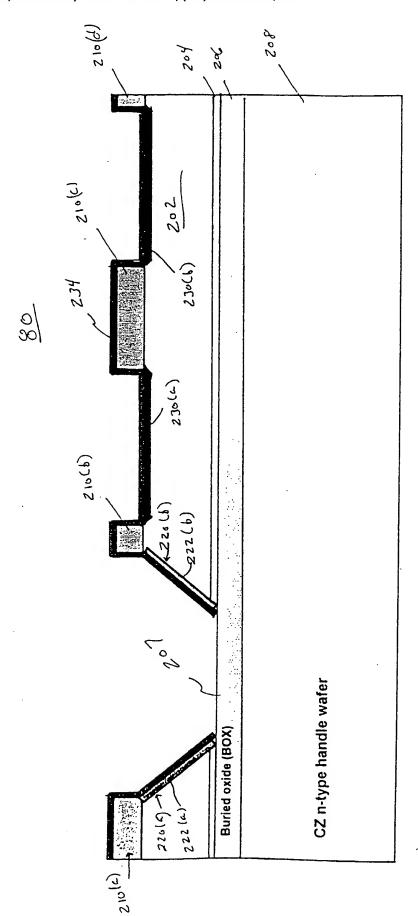


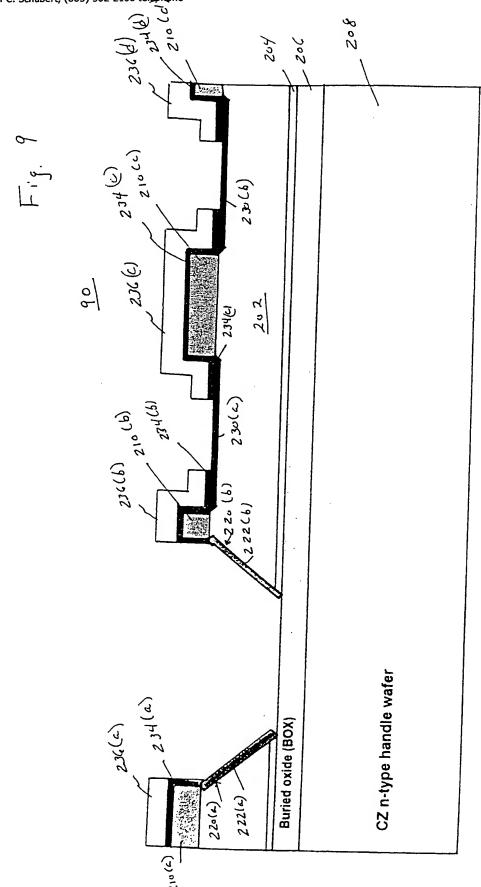


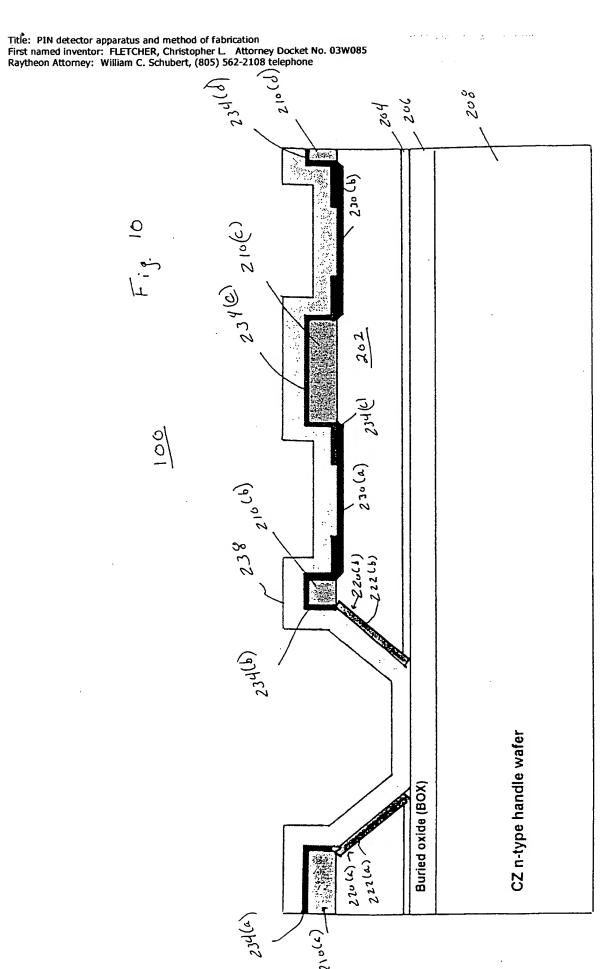


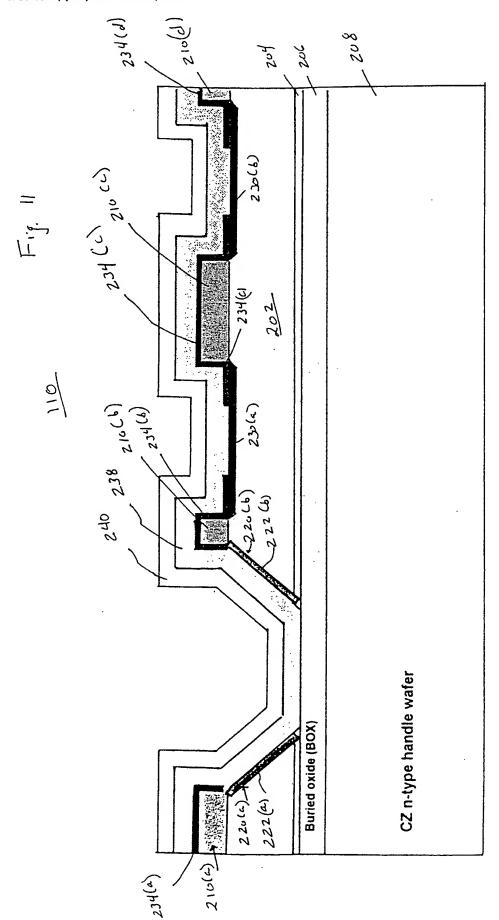
Title: PIN detector apparatus and method of fabrication First named inventor: FLETCHER, Christopher L. Attorney Docket No. 03W085 Raytheon Attorney: William C. Schubert, (805) 562-2108 telephone

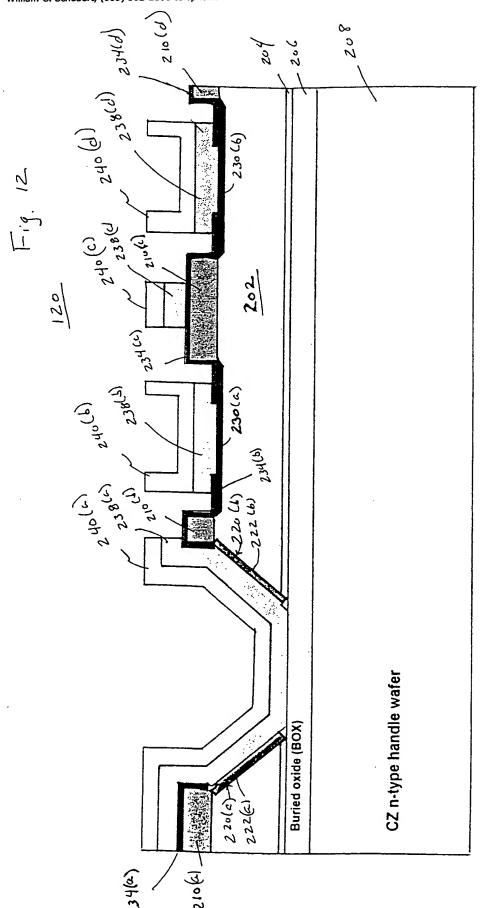




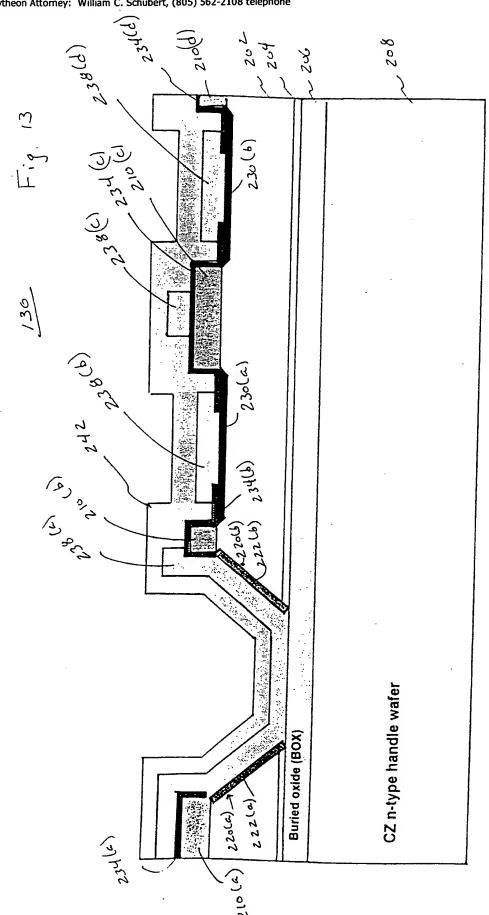




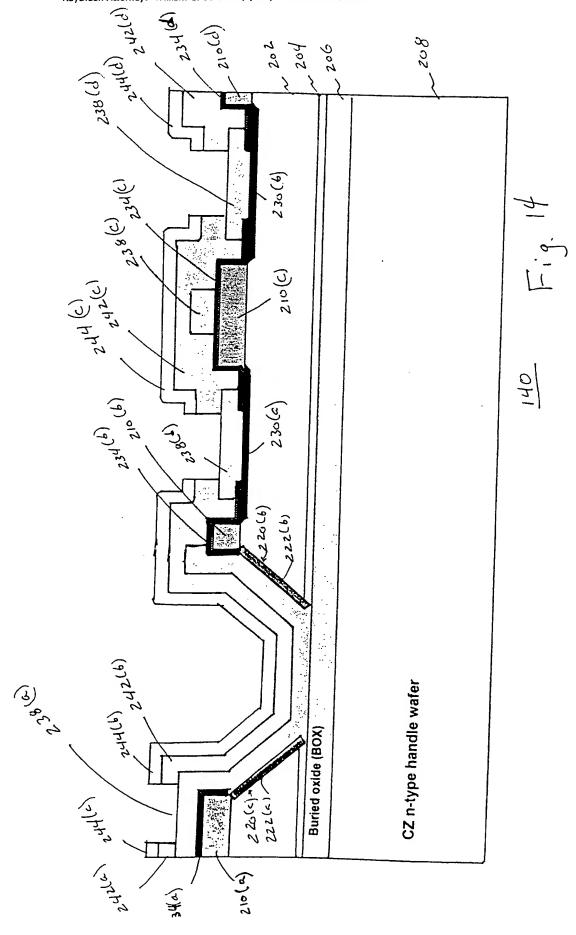


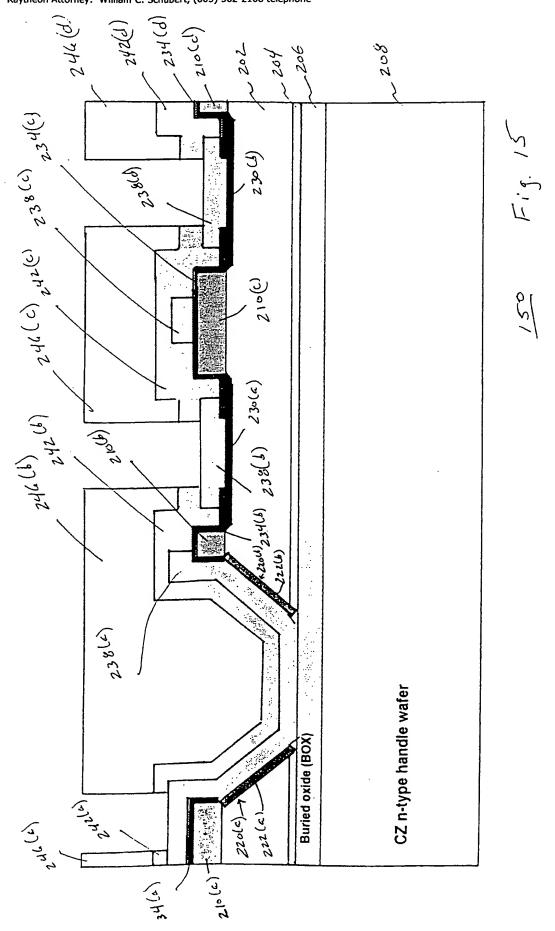


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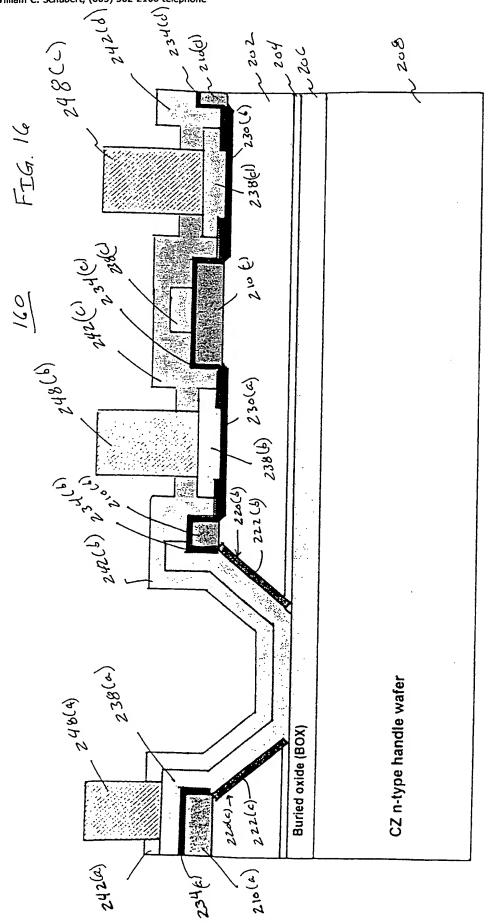


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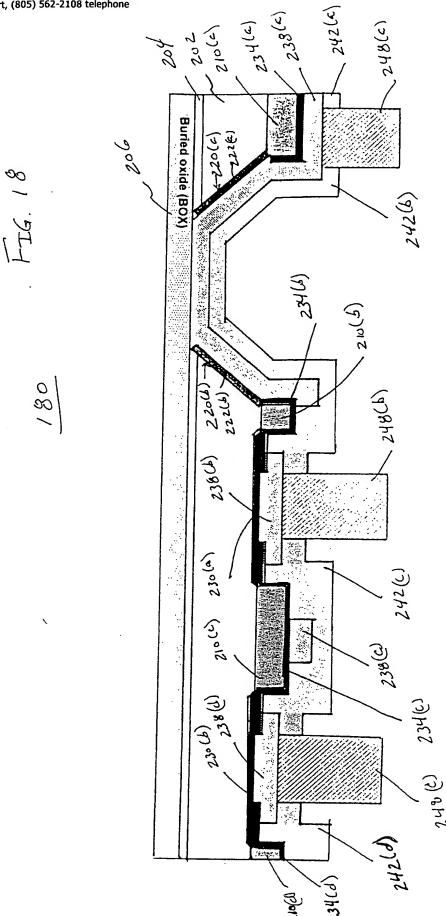


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First named inventor: FLETCHER, Christopher L. Attorney Docket No. 03W085
Raytheon Attorney: William C. Schubert, (805) 562-2108 telephone CZ n-type handle wafer Buried oxide (BOX) 2226 20 (a) 220(6) 230(4) 234(6) 238(6) 242(6) (2)012 , 234(d)

F19. 17



234(4)